

TO-252 N MOS
N-CHANNEL MOSFET in a TO-252 Plastic Package.

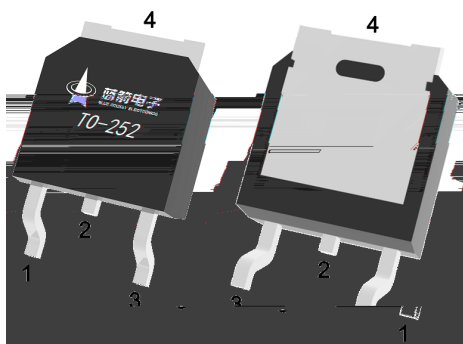
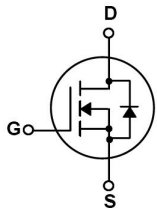
$V_{DS}=60V$; $I_D=20A$
 $R_{DS(ON)}@10V \leq 37m\Omega$ (Type.25m Ω)
 $R_{DS(ON)}@4.5V \leq 42m\Omega$ (Type.30m Ω)

AEC-Q101
HF Product.

Qualified to AEC-Q101 Standards for High Reliability,

LED

Boost converters and synchronous rectifiers for consumer, telecom, industrial power supplies and LED backlighting, Meet the stringent requirements of automotive applications.

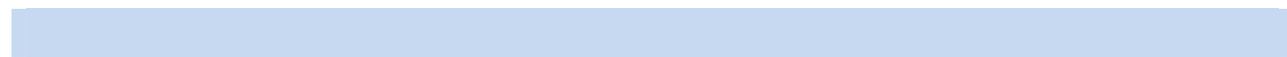


PIN1 G PIN 2 D PIN 3 S PIN 4 D

See Marking Instructions.

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	60	V
Drain Current	$I_D(T_C=25^\circ\text{C})$	20	A
Drain Current - Pulsed	I_{DM}	47	A
Gate-Source Voltage	V_{GS}	± 20	V
Avalanche energy(L=0.5mH)	E_{AS}	58	mJ
Avalanche Current(L=0.5mH)	I_{AS}	13	A
Power Dissipation	$P_D(T_C=25^\circ\text{C})$	33.6	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to 150	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	65	/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	3.7	/W

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\mu A$	60			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V$ $V_{GS}=0V$			1	μA
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=V_{GS}$				μA



Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=30V$ $R_L=2.5\Omega$ $R_{GEN}=3.0\Omega$		4.2		ns
Turn-On Rise Time	t_r			3.4		
Turn-Off Delay Time	$t_{d(off)}$			16		
Turn-Off Fall Time	t_f			2		

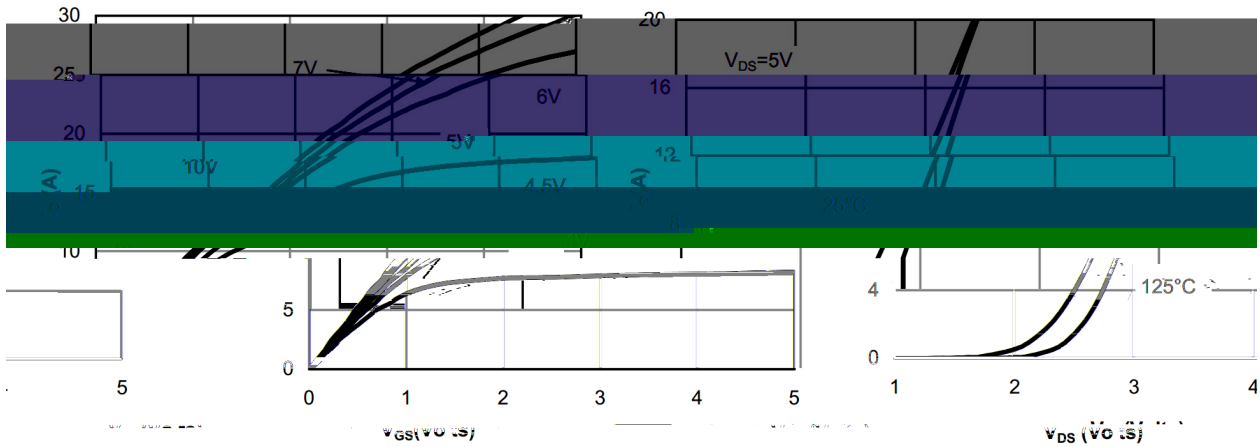


Figure 2: Transfer Characteristics

Figure 1: On-Region Characteristics

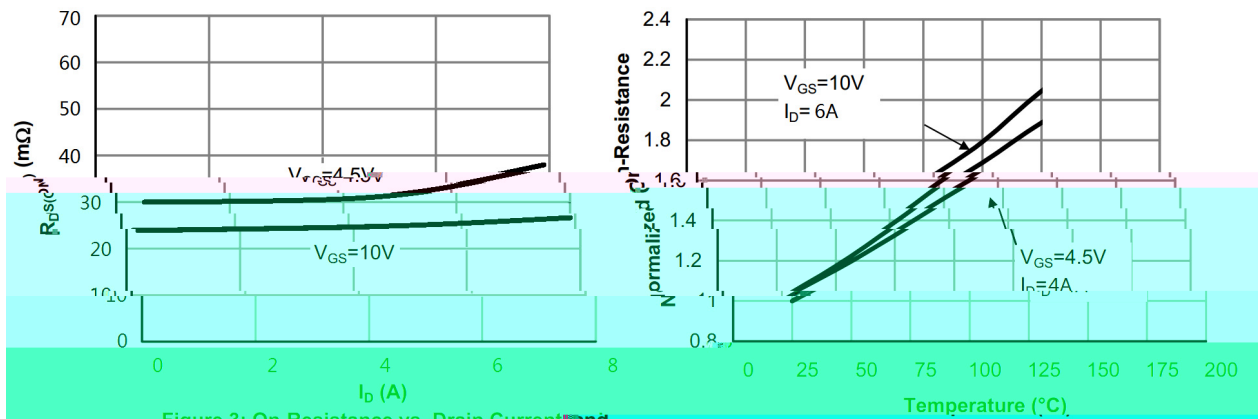


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

Figure 4: On-Resistance vs. Junction Temperature

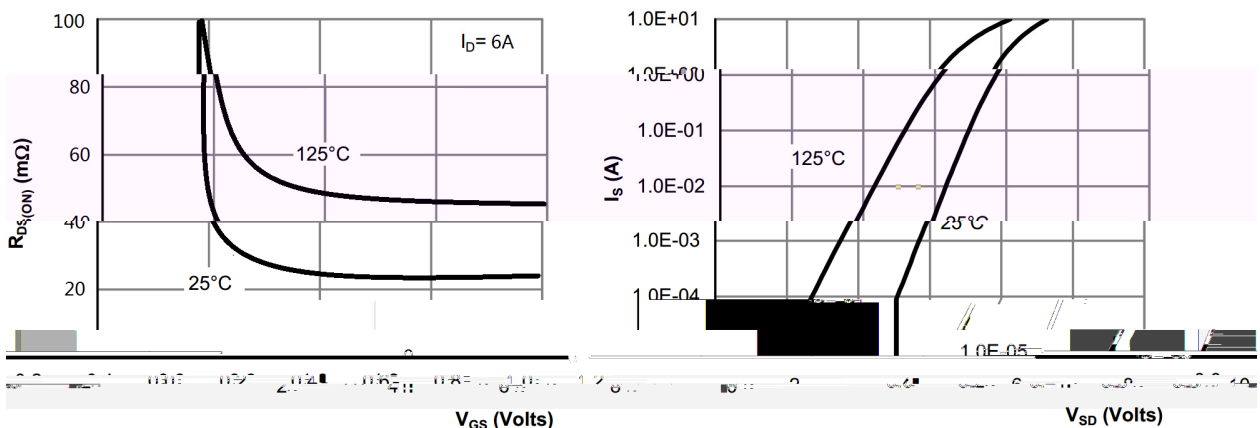


Figure 5: On-Resistance vs. Gate-Source Voltage

Figure 6: Body-Diode Characteristics

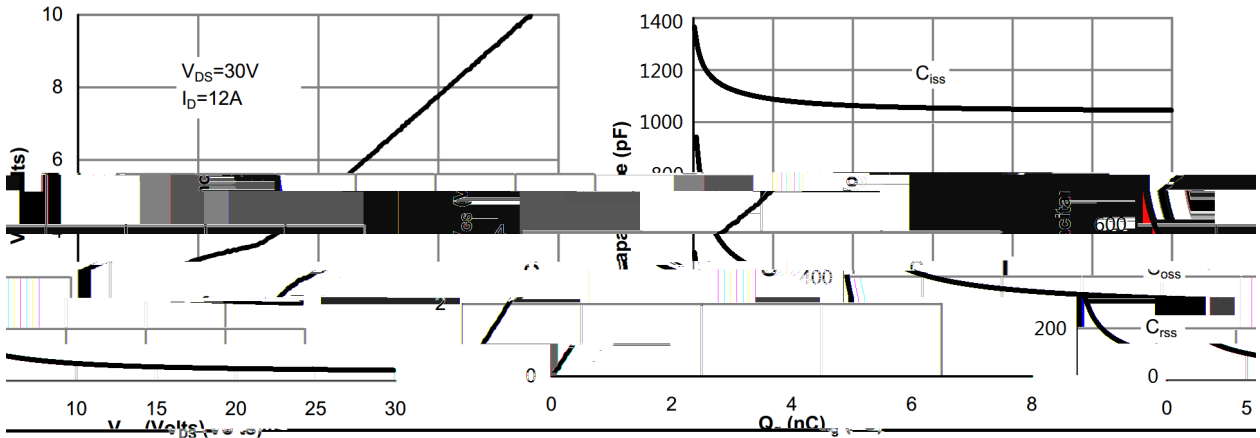


Figure 6: Output Characteristics

Figure 7: Gate-Charge Characteristics

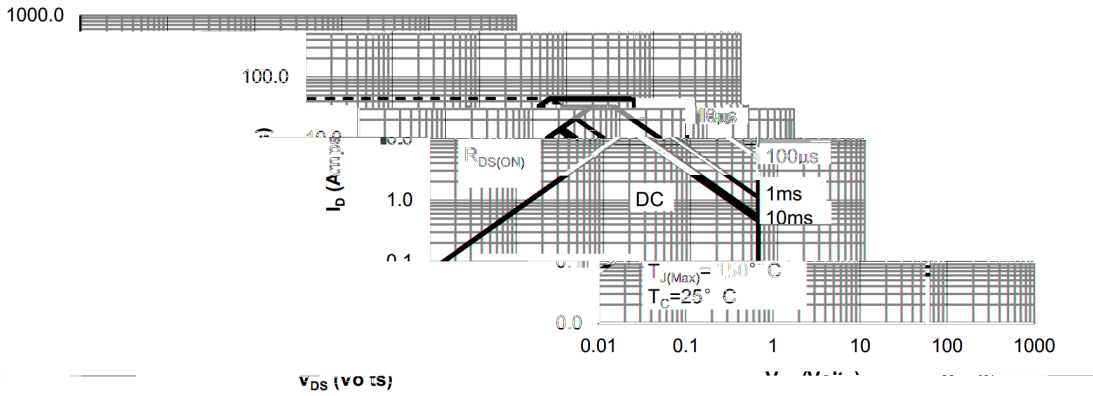


Figure 9: Maximum Forward Biased Safe Operating Area

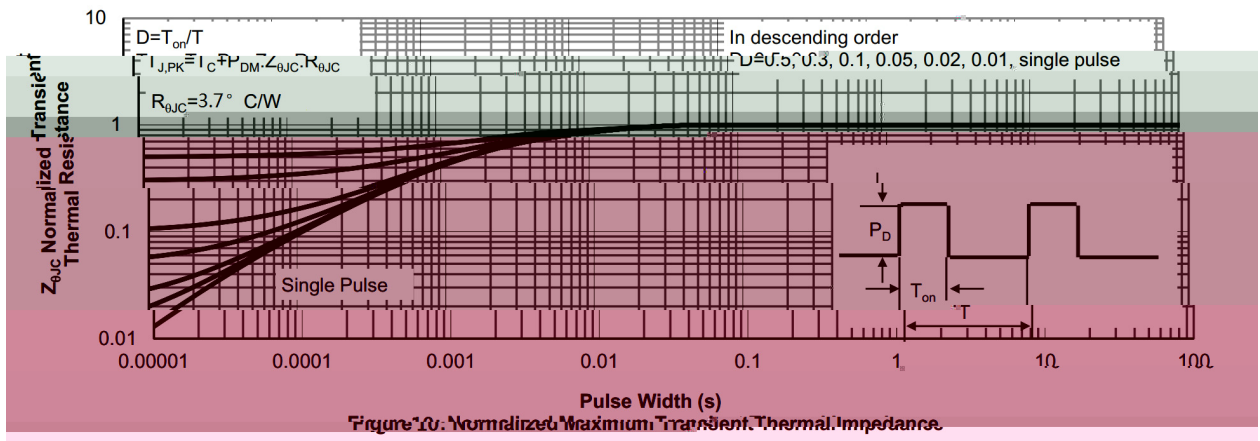
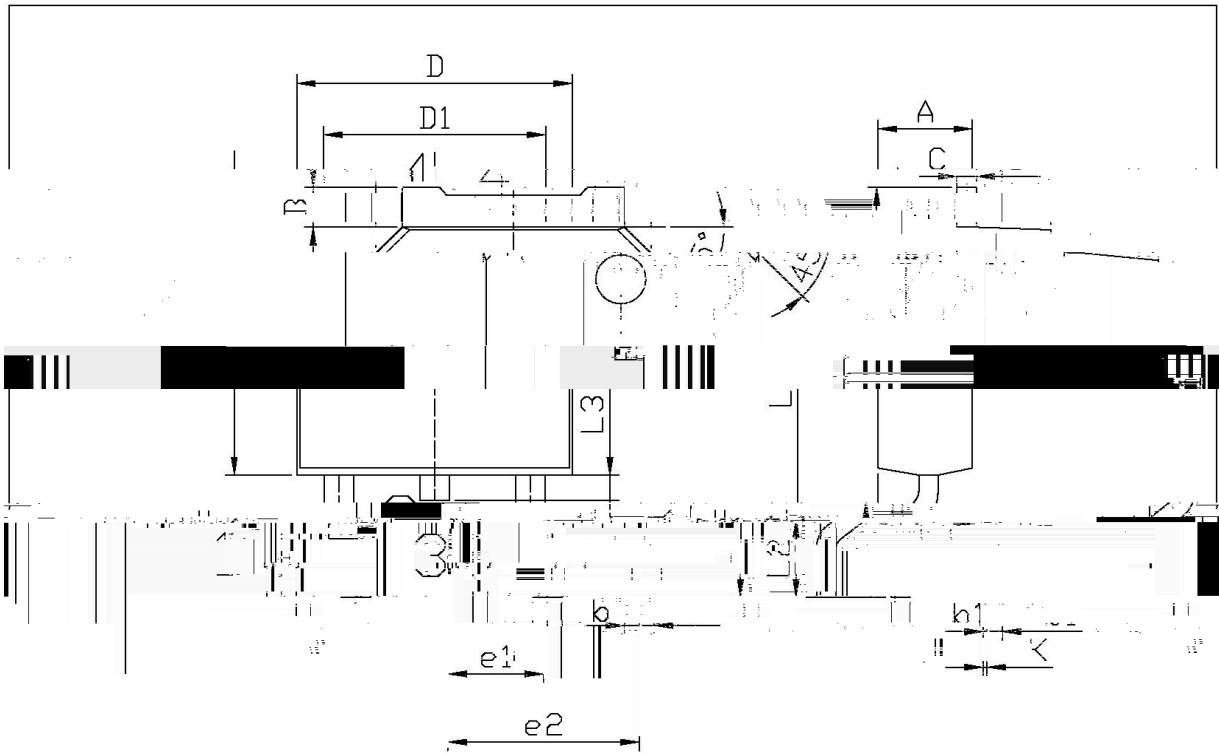


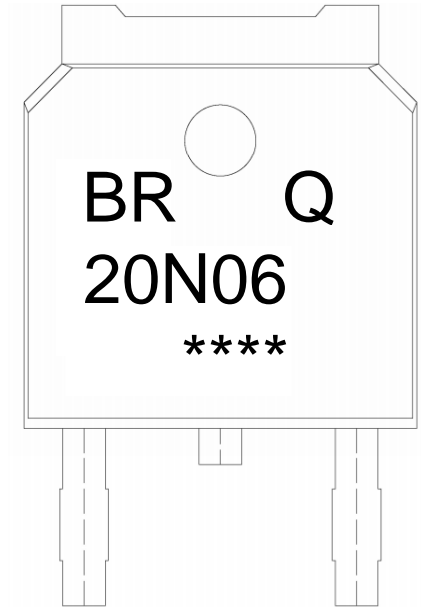
Figure 10: Normalized Maximum Transient Thermal Impedance



单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min.	Max.		Min.	Max.
A	6.25		A	2.40	5
B	2.34		B	1.25	2
C	4.73		C	0.90	1
D	9.85	10.35	b1	0.45	0.55
L3	0.45	0.55	D	1.70	3.90
L3	0.60	0.90	D1	6.45	6.75

TO-252



BR

Q

20N06

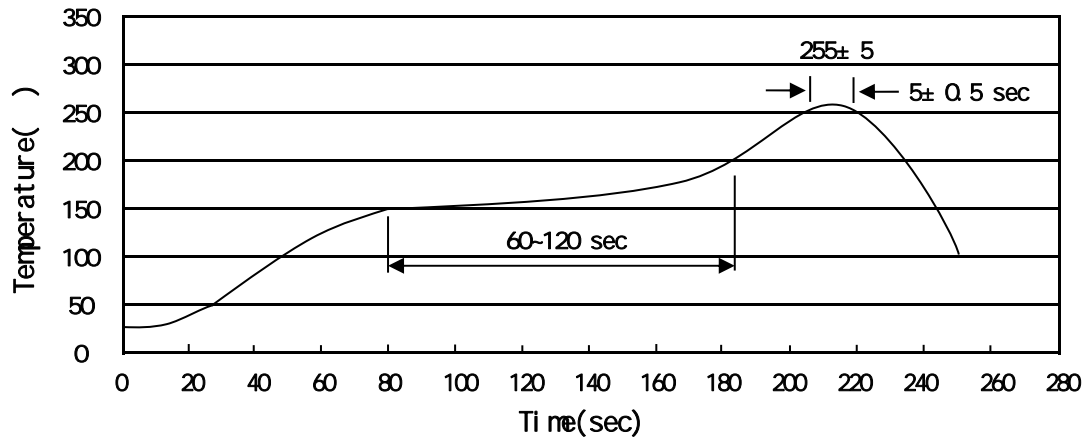
Note:

BR: Company Code

Q: Automobile halogen-free product Code

20N06: Product Type Code

****: Lot No. Code, code change with Lot No

Temperature Profile for IR Reflow Soldering(Pb-Free)


Note:

- | | | | | | |
|---|-------|-----|-----------|---------|---|
| 1 | 150 | 200 | 60 | 120sec; | 1.Preheating:150~200 , Time:60~120sec. |
| 2 | 255±5 | | 5±0.5sec; | | 2.Peak Temp.:255±5 , Duration:5±0.5sec. |
| 3 | | | 2~10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

260±5

10±1 sec.

Temp.:260±5

Time:10±1 sec

/ REEL

Package Type	Units					Dimension (unit mm ³)		
TO-252	2,500	2	5,000	6	30,000	13 x16	360x360x50	380x335x366

/ TUBE

Package Type	Units					Dimension (unit mm ³)		
TO-251/252	75	48	3,600	5	18,000	526x20.5x5.25	555x164x50	575x290x180